

1N3611 1N3613
1N3612 1N3614
1N3957

GLASS PASSIVATED
SILICON RECTIFIERS
1.0 AMP, 200 THRU 1000 VOLT



GPR-1A CASE



www.centrasemi.com

DESCRIPTION:

The CENTRAL SEMICONDUCTOR 1N3611 thru 1N3614, and 1N3957 are hermetically sealed, glass passivated, general purpose silicon rectifiers ideal for commercial, military, automotive and entertainment applications requiring high reliability and failure free performance.

MARKING: FULL PART NUMBER

MAXIMUM RATINGS: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

	SYMBOL	1N3611	1N3612	1N3613	1N3614	1N3957	UNITS
Peak Repetitive Reverse Voltage	V_{RRM}	200	400	600	800	1000	V
DC Blocking Voltage	V_R	200	400	600	800	1000	V
RMS Reverse Voltage	$V_{R(RMS)}$	140	280	420	560	700	V
Average Forward Current ($T_A=100^{\circ}\text{C}$)	I_O			1.0			A
Peak Forward Surge Current, $t_p=8.3\text{ms}$	I_{FSM}			40			A
Operating and Storage Junction Temperature	T_J, T_{stg}			-65 to +175			$^{\circ}\text{C}$

ELECTRICAL CHARACTERISTICS: ($T_A=25^{\circ}\text{C}$ unless otherwise noted)

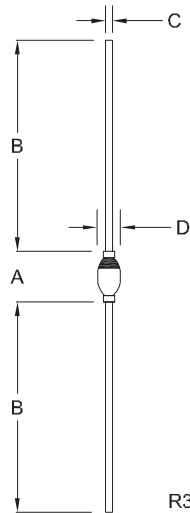
SYMBOL	TEST CONDITIONS	TYP	MAX	UNITS
I_R	$V_R=\text{Rated } V_{RRM}$		5.0	μA
I_R	$V_R=\text{Rated } V_{RRM}, T_A=150^{\circ}\text{C}$		200	μA
V_F	$I_F=1.0\text{A}$		1.1	V
C_J	$V_R=4.0\text{V}, f=1.0\text{MHz}$	25		pF
t_{rr}	$I_F=0.5\text{A}, I_R=1.0\text{A}, I_{rr}=0.25\text{A}$		2.0	μs

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GPR-1A CASE - MECHANICAL OUTLINE



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	-	0.240	-	6.10
B	1.000	-	25.40	-
C	0.028	0.034	0.71	0.86
D	0.070	0.150	1.80	3.81

GPR-1A (REV: R3)

MARKING: FULL PART NUMBER

R1 (28-February 2013)